國立中正大學 113 學年度碩士班招生考試

試 題

[第2節]

科目名稱	電子學
条所組別	電磁晶片組 電機工程學系-計算機工程組 晶片系統組

-作答注意事項-

- ※作答前請先核對「試題」、「試卷」與「准考證」之<u>系所組別、科目名稱</u>是否 相符。
- 1. 預備鈴響時即可入場,但至考試開始鈴響前,不得翻閱試題,並不得書寫、 畫記、作答。
- 2. 考試開始鈴響時,即可開始作答;考試結束鈴響畢,應即停止作答。
- 3.入場後於考試開始 40 分鐘內不得離場。
- 4.全部答題均須在試卷(答案卷)作答區內完成。
- 5.試卷作答限用藍色或黑色筆(含鉛筆)書寫。
- 6. 試題須隨試卷繳還。

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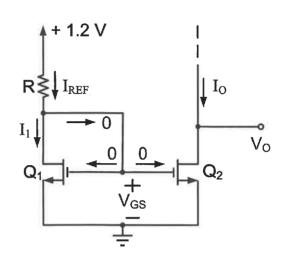
科目名稱:電子學

本科目共 2 頁 第 1 頁

系所組別:電機工程學系-電磁晶片組、計算機工程組、晶片系統組

If a parameter un-given in the question, you can specify it in the answer sheet.

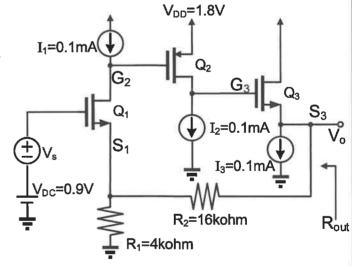
- 1. (20%) For an output current whose nominal value is 100 μ A, and Q₁ and Q₂ are matched with channel length of 0.5 μ m, channel widths of 5 μ m, V_t=0.4 V and k'_n =500 μ A/V². Early voltage is 5 V/ μ m.
 - (a) (5%) What is the required value of R?
 - (b) (5%) What is the lowest possible value of V₀?
 - (c) (5%) Find the output resistance of current source.
 - (d) (5%) Find the change in output current resulting from a +0.5 V change in V_o .



- 2. (20%) Three MOSFETs are sized to operate at $|V_{ov}|$ =0.3V. Let $|V_t|$ =0.5V and $|V_A|$ =20V, the current sources utilize single transistors and thus have output resistances equal to r_o .
 - (a) (5%)If Vs has a zero dc component, find the dc voltages at nodes S1, G2, S3, and G3.

Verify that each of the current sources has the minimum required dc voltage across it for proper operation.

- (b) (5%) Calculate the gain of each of these three stages and the overall voltage gain, A.
- (c) (5%) Find $A_f = Vo/Vs$.
- (d) (5%) Find the output resistance.



- 3. (20%) An NMOS transistor operating in the triode region with v_{DS} =0.3V conducts 50 μ A for v_{GS} =2V and 100 μ A for v_{GS} =3V, respectively.
 - (a) (5%) What is the corresponding value of threshold voltage V_{th} ?
 - (b) (5%) If $k_n' = \mu_n C_{ox} = 20\mu A/V^2$, what is the device aspect ratio?
 - (c) (5%) What current would be excepted to flow with v_{GS} =2.8V and v_{DS} =0.25V?
 - (d) (5%) If it operates at v_{DS} =2V, at what value of v_{GS} will the drain-end of the MOSFET channel just become pinch-off.

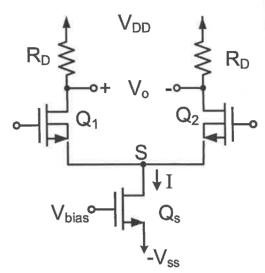
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科目名稱:電子學

本科目共2頁 第2頁

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4. (20%) The current source in a MOSFET differential amplifier provides constant current $I=500~\mu A$ and its equivalent resistance R_{SS} and capacitance C_{SS} are $100~k\Omega$ and 0.1fP, respectively. The parameters of Q_1 and Q_2 are $V_A=25V$, $C_{gs}=30fF$, $C_{gd}=5fF$, and $C_{db}=5fF$. The drain resistor R_D is $30~k\Omega$. Transistors are biased with overdrive voltage $V_{ov}=0.3~V$. Also, there is a 100fF capacitive load (C_L) existed between each drain and ground.



- (a) (5%) Find the mid-band differential gain A_d . (5%)
- (b) (5%) If the series resistance (R_{sig}) of input signal source for each gate terminal is $20\text{k}\Omega$, please estimate the upper 3-dB frequency f_H by open-circuit time-constant method.
- (c) (5%) Find the common-mode gain response $A_{cm}(j\omega)$.
- (d) (5%) Which is the dominate corner frequency in CMRR response.
- 5. (20%) A noninverting op amp provides a direct implementation of the feedback loop. Assume that the op amp has infinite input resistance and zero output resistance.
 - (a) (5%) Find an expression for the feedback factor β .
 - (b) (5%) If the open-loop voltage gain $A=10^5$, find R_2/R_1 to obtain a closed-loop voltage gain A_f of 10
 - (c) (5%) What is the amount of feedback in decibels?
 - (d) (5%) If $V_s = 1V$, find V_o , V_f , and V_i .

